

# A Fullwave CAD Tool for Waveguide Components Using a High Speed Direct Optimizer

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**Abstract**—An extremely efficient optimization tool, where the fullwave mode matching simulator is driven by a quasi-Newton optimizer using the adjoint network method, has been developed for the CAD of a class of rectangular waveguide components. This includes filters, phase shifters, branch guide couplers, etc., with step in either the E- or H-plane. With respect to the conventional finite difference computation of the derivatives, a speedup factor of more than 10 times is easily achieved.

## I. INTRODUCTION

WAVEGUIDE technology is still the key technology in many applications, and particularly in space applications [1], [2]. The availability of rigorous and efficient CAD tools is of paramount importance in order to reduce time and costs associated with tuning and trimming of the components.

Design techniques based on rigorous fullwave models must be used to obtain the required accuracy. In spite of the recent improvements in the efficiency of fullwave methods, such as the mode matching technique, these methods usually involve significant computer expenditures. The optimization of a single component may easily require hundreds or thousands analyses. As a consequence, the CAD of components with tenths or hundreds degrees of freedom may easily become unaffordable even with the most efficient fullwave analysis tools. To keep the computer effort within affordable limits it is therefore necessary to adopt very efficient optimization algorithms.

A novel implementation of gradient-based optimization methods, the adjoint network method (ANM), has recently been presented which permits an extremely efficient evaluation of the gradient of the objective function [3]. Since ANM avoids the finite difference evaluation of the multidimensional gradient of the objective function, its efficiency increases with the number of the degrees of freedom, thus the complexity of the circuit.

Based on ANM, we have developed an extremely efficient CAD tool of a class of rectangular waveguide components such as filters, phase shifters, and branch guide couplers realized with steps in either the E- or H-plane, as depicted in Fig. 1. The tool consists of a direct optimization-driven fullwave simulator based on a modified mode matching technique [4]. A high accuracy combined with high efficiency are achieved by joining the rigorous electromagnetic simulator with the ANM optimization procedure. A number of waveguide components

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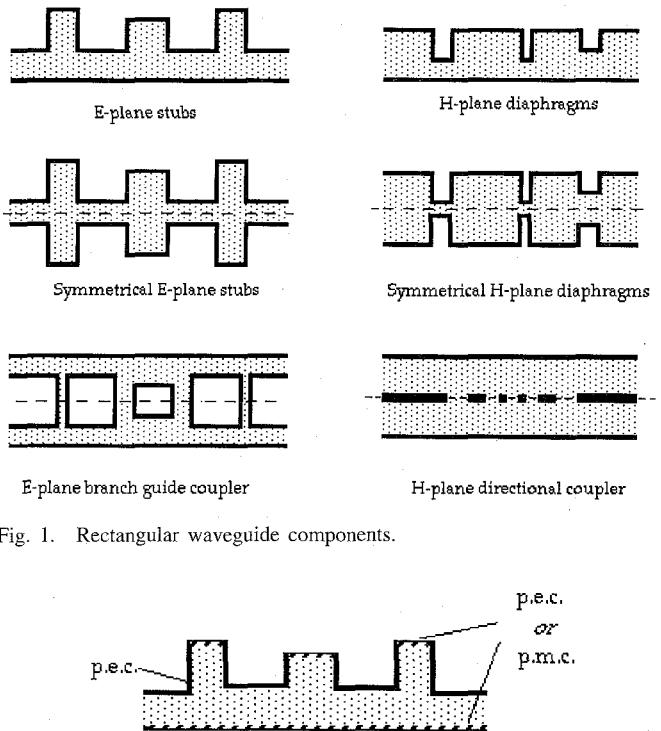


Fig. 1. Rectangular waveguide components.

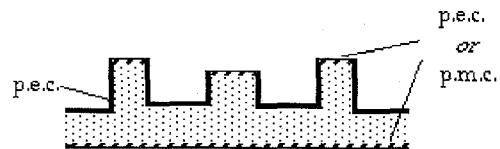


Fig. 2. Schematic of the basic waveguide structure.

have been designed and tested showing very satisfactory results.

## II. MODELING OF THE BASIC WAVEGUIDE STRUCTURE

Fig. 1 shows the schematic of different waveguide structures. They can all be reduced to the same basic structure (Fig. 2) consisting of a waveguide section loaded with either E- or H-plane stubs; the latter are terminated by either perfect electric conductor (PEC) or perfect magnetic conductor (PMC). The waveguide dimension ("a" or "b") can also vary from section to section. A number of different components such as filters, fixed phase shifters, branch-guide couplers either in the E- or H-plane [5]–[7] can be reduced to the basic structure of Fig. 2.

A rigorous and efficient analysis of Fig. 2 can be performed using the so called cellular segmentation technique [4]. This consists of partitioning the geometry into the cascade of rectangular cells. Each cell represents a stub or a waveguide section and is modeled as a multiport network in terms of the Generalized Admittance Matrix (GAM). An example of

cellular segmentation of a three-stub waveguide structure is depicted in Fig. 3.

The derivation of the GAM for the uniform waveguide section and for the stub is illustrated next. Consider first a uniform waveguide section of length  $L$ . The electromagnetic (EM) field is expanded in terms of an orthonormalized set of modes  $\mathbf{e}_n, \mathbf{h}_n$  of the waveguide

$$\begin{aligned}\mathbf{E}_t &= \sum_{n=1}^M V_n(z) \mathbf{e}_n(x, y) \\ \mathbf{H}_t &= \sum_{n=1}^M I_n(z) \mathbf{h}_n(x, y)\end{aligned}\quad (1)$$

$\mathbf{E}_t, \mathbf{H}_t$  being the transverse EM field components, and  $M$  the number of modes taken into consideration. The GAM constitutes the matrix relation between the  $V$ 's and  $I$ 's coefficients at both ends of the waveguide length  $L$ . Using the transmission line theory, by virtue of the orthogonality of the modal eigenfunctions, one easily obtains

$$\mathbf{Y}_g = \begin{bmatrix} \mathbf{Y}_{g11} & \mathbf{Y}_{g12} \\ \mathbf{Y}_{g21} & \mathbf{Y}_{g22} \end{bmatrix} \quad (2)$$

where  $\mathbf{Y}_{gij}$  are diagonal submatrices of size  $M \times M$  given by

$$\begin{aligned}\mathbf{Y}_{g11} = \mathbf{Y}_{g22} &= \text{diag} \left[ \frac{-jY_{Cm}}{\tan(\beta_m l)} \right] \\ \mathbf{Y}_{g12} = \mathbf{Y}_{g21} &= \text{diag} \left[ \frac{-jY_{Cm}}{\sin(\beta_m l)} \right] \quad m = 1, 2 \dots M\end{aligned}\quad (3)$$

where  $\beta_m$  is the phase constant and  $Y_{Cm}$  the characteristic admittance of the  $m$ th mode. The stub structure can be regarded as the cascade of three waveguide sections A, B, C, the central B section being larger than the other ones. We assume the terminal sections A and C as having zero length. Depending on whether E- or H-plane stubs are considered, the fields within the cell are expanded in terms of LSE or TE modes respectively. To obtain the GAM of the stub, the mode matching technique is applied to the step discontinuities A-B and B-C. For the GAM  $\mathbf{Y}_s$  of the stub one obtains

$$\begin{aligned}\mathbf{Y}_s &= \begin{bmatrix} \mathbf{Y}_{s11} & \mathbf{Y}_{s12} \\ \mathbf{Y}_{s21} & \mathbf{Y}_{s22} \end{bmatrix} \\ &= \begin{bmatrix} \mathbf{W}_{AB} & \mathbf{0} \\ \mathbf{0} & \mathbf{W}_{CB} \end{bmatrix} \\ &\quad \cdot \mathbf{Y}_g \cdot \begin{bmatrix} \mathbf{W}_{AB}^T & \mathbf{0} \\ \mathbf{0} & \mathbf{W}_{CB}^T \end{bmatrix}\end{aligned}\quad (4)$$

where  $W_{AB}$  is the coupling matrix between the A and B waveguides and  $W_{BC}$  is the coupling matrix between the B and C waveguides

$$W_{AB\,nm} = \int_{SA} \mathbf{e}_{nA} \cdot \mathbf{e}_{mB} dS. \quad (5)$$

As noted above, for optimum efficiency of the algorithm, different modal sets are to be used depending on the type of step discontinuities. Expressions for the coupling matrices for both E- and H-plane discontinuities are given in the Appendix.

The total  $\mathbf{Y}$  matrix of the entire two port network can be build up by cascading the GAM matrix of the individual

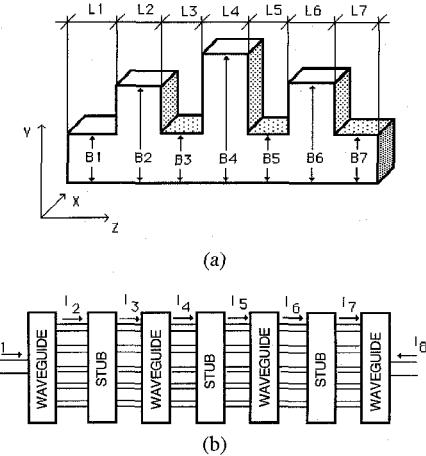


Fig. 3. (a) A 3-stub waveguide structure (b) and its generalized equivalent circuit.

cells (i.e., stubs and waveguide sections). This completes the characterization of the waveguide component. Observe that, for simplicity, we will assume that the reference planes of the component are put far away from the nearest discontinuities, in such a way that higher order modes at those planes can be neglected. The component can thus be characterized by a  $2 \times 2$  admittance matrix relative to the dominant modes.

In view of the application of the ANM described in the next section, however, the additional information of the voltages at the internal or connected ports is required. As a consequence, a different algorithm has been developed in order to compute with minimum effort all the information required for implementation of the ANM.

Consider the cascade of multiport networks sketched in Fig. 3(b). Let  $\mathbf{V}_n(\mathbf{I}_n)$  be the voltage (current) vector at port  $n$  (with  $n = 1 \dots N$ ) composed of  $M_n$  elements corresponding to the  $M_n$  modes at the port  $n$ . Using the notation of Fig. 3(b) we can write, for the first network

$$\begin{bmatrix} \mathbf{I}_1 \\ -\mathbf{I}_2 \end{bmatrix} = \begin{bmatrix} \mathbf{Y}_{11}^1 & \mathbf{Y}_{12}^1 \\ \mathbf{Y}_{21}^1 & \mathbf{Y}_{22}^1 \end{bmatrix} \begin{bmatrix} \mathbf{V}_1 \\ \mathbf{V}_2 \end{bmatrix}. \quad (6)$$

For the internal  $k$ th network connected between port  $k$  and  $k+1$  we have

$$\begin{bmatrix} \mathbf{I}_k \\ -\mathbf{I}_{k+1} \end{bmatrix} = \begin{bmatrix} \mathbf{Y}_{11}^k & \mathbf{Y}_{12}^k \\ \mathbf{Y}_{21}^k & \mathbf{Y}_{22}^k \end{bmatrix} \begin{bmatrix} \mathbf{V}_k \\ \mathbf{V}_{k+1} \end{bmatrix} \quad k = 2, \dots, N-2. \quad (7)$$

For the last  $(N-1)$ th network we have

$$\begin{bmatrix} \mathbf{I}_{N-1} \\ -\mathbf{I}_N \end{bmatrix} = \begin{bmatrix} \mathbf{Y}_{11}^{N-1} & \mathbf{Y}_{12}^{N-1} \\ \mathbf{Y}_{21}^{N-1} & \mathbf{Y}_{22}^{N-1} \end{bmatrix} \begin{bmatrix} \mathbf{V}_{N-1} \\ \mathbf{V}_N \end{bmatrix}. \quad (8)$$

All currents at the connected (internal) ports  $k = 2 \dots N-1$  can immediately be eliminated from (6)–(8). We obtain the following set of  $N-2$  equations in the  $N-2$  voltages at the connected ports

$$\begin{aligned} &[\mathbf{Y}_{22}^1 + \mathbf{Y}_{11}^2] \mathbf{V}_2 + \mathbf{Y}_{12}^2 \mathbf{V}_3 \\ &\quad = -\mathbf{Y}_{21}^1 \mathbf{V}_1 \\ &\mathbf{Y}_{21}^{k-1} \mathbf{V}_{k-1} + [\mathbf{Y}_{22}^{k-1} + \mathbf{Y}_{11}^k] \mathbf{V}_k + \mathbf{Y}_{12}^k \mathbf{V}_{k+1} \\ &\quad = 0 \quad k = 3, 4 \dots N-2 \\ &\mathbf{Y}_{21}^{N-2} \mathbf{V}_{N-2} + [\mathbf{Y}_{22}^{N-2} + \mathbf{Y}_{11}^{N-1}] \mathbf{V}_{N-1} \\ &\quad = -\mathbf{Y}_{12}^{N-1} \mathbf{V}_N.\end{aligned}\quad (9)$$

The solution of the above system gives the voltage distribution at the connected ports for any excitation at the external ports 1 and  $N$ . The currents at the external ports are then computed from the remaining equations, i.e., the first of (6) and the last of (8)

$$\begin{aligned}\mathbf{I}_1 &= \mathbf{Y}_{11}^1 \mathbf{V}_1 + \mathbf{Y}_{12}^1 \mathbf{V}_2 \\ -\mathbf{I}_N &= \mathbf{Y}_{21}^{N-1} \mathbf{V}_{N-1} + \mathbf{Y}_{22}^{N-1} \mathbf{V}_N.\end{aligned}\quad (10)$$

The  $2 \times 2$  admittance matrix, then the scattering matrix, of the entire network can finally be evaluated by straightforward algebra.

### III. QUASI-NEWTON OPTIMIZATION BY THE ANM

Based on a fullwave analysis technique, a rigorous description of the waveguide component as a two port microwave network has been described in the previous section. To achieve a prescribed frequency response, we need to modify its dimensions according to a suitable optimization strategy, so as to minimize a properly defined objective function.

Different objective functions can be used, depending on the type of response required. For example, the following function can be used for the optimization of a filter

$$\begin{aligned}F = \sum_{i=1}^{NF} & \{K_{1i}[|s_{11}(f_i)| - |S_{11}^{ob}|]^2 \\ & + K_{2i}[|s_{21}(f_i)| - |S_{21}^{ob}|]^2\}\end{aligned}\quad (11)$$

where  $f_i$  is the  $i$ th frequency in the prescribed band,  $K_{1i}$ ,  $K_{2i}$  are weighting coefficients,  $|s_{11}^{ob}|$ ,  $|s_{21}^{ob}|$  are the required amplitudes of the scattering parameters (in dB).

Efficiency of the optimization strategy is of paramount importance, since the analysis technique, although efficient, still involves a considerable numerical effort. Optimization methods based on the knowledge of the gradient of the objective function, i.e., its first derivatives with respect to all geometrical parameters, appear to be the most efficient ones. In this paper, the quasi-Newton method [8] with BFGS updating formula [12] has been used.

A considerable numerical effort is usually involved in the computation of the gradient of the objective function. The effort increases with the complexity of the component and with the number of geometrical parameters that have to be optimized. One has, in fact, to compute the derivatives of the objective function with respect to all free geometrical parameters of the component. Conventionally, the derivatives are computed by numerical differentiation, i.e., by performing one additional analysis of the device for a small increment of each free parameter. The computation of the gradient thus requires a number of additional analyses of the device equal to the number of free parameters. In the example of Fig. 3, assuming the dimensions of the feeding waveguides to be given, we have 10 degrees of freedom. Therefore, 10 additional full wave analyses are required for each gradient evaluation.

Based on Tellegen's theorem, the adjoint network method is well known in circuit theory [9]–[11]. For a reciprocal network, all partial derivatives of the objective function of a reciprocal network can be computed by ANM using only

one complete analysis of the network. Dramatic computation savings, particularly when the method is used in connection with full wave models of microwave structures, can thus be obtained. The derivation of the basic formula of the ANM is briefly described here using an admittance matrix description of the microwave networks.

Tellegen's theorem states that for a pair of networks which are topologically identical the following equations hold

$$\begin{aligned}\mathbf{V}^T \bar{\mathbf{I}} &= 0 \\ \mathbf{I}^T \bar{\mathbf{V}} &= 0\end{aligned}\quad (12)$$

where  $\mathbf{V}$  and  $\bar{\mathbf{I}}$  are branch voltage and current vectors on the two networks and  $T$  stands for transpose.

Consider now a microwave network. The incremental changes  $\Delta \mathbf{V}$ ,  $\Delta \mathbf{I}$  produced by a perturbation of its elements satisfy the Kirchoff's laws and Tellegen's theorem. From (12) one therefore obtains

$$\Delta \mathbf{V}^T \bar{\mathbf{I}} - \Delta \mathbf{I}^T \bar{\mathbf{V}} = 0. \quad (13)$$

Using an admittance matrix description and neglecting higher order terms, the current incremental change can be expressed as

$$\Delta \mathbf{I} = \mathbf{Y} \Delta \mathbf{V} + \Delta \mathbf{Y} \mathbf{V}.$$

Substituting into (13) gives

$$\Delta \mathbf{V}^T \bar{\mathbf{I}} - \Delta \mathbf{I}^T \bar{\mathbf{V}} = \Delta \mathbf{V}^T \bar{\mathbf{I}} - \Delta \mathbf{V}^T \mathbf{Y}^T \bar{\mathbf{V}} - \mathbf{V} \Delta \mathbf{Y}^T \bar{\mathbf{V}}. \quad (14)$$

Suppose now that the following relation holds

$$\bar{\mathbf{I}} = \mathbf{Y}^T \bar{\mathbf{V}}. \quad (15)$$

We obtain from (14)

$$\Delta \mathbf{V}^T \bar{\mathbf{I}} - \Delta \mathbf{I}^T \bar{\mathbf{V}} = -\mathbf{V}^T \Delta \mathbf{Y}^T \bar{\mathbf{V}}. \quad (16)$$

Equation (15) defines the adjoint network which is characterized by the transposed of the  $Y$  matrix of the original network. It is remarkable that a reciprocal network is equal to its adjoint network.

Consider now the case of a global network composed of  $N-1$  subnetworks. Equation (4) can be generalized as follows

$$\Delta \mathbf{V}_{Ext}^T \bar{\mathbf{I}}_{Ext} - \Delta \mathbf{I}_{Ext}^T \bar{\mathbf{V}}_{Ext} \bar{\mathbf{V}}_{Ext} = - \sum_{n=1}^{N-1} \mathbf{V}_n^T \Delta \mathbf{Y}_n^T \bar{\mathbf{V}}_n \quad (17)$$

where the index “ext” refers to the external ports of the global network,  $\mathbf{V}_n$  and  $\mathbf{V}_n$  are the voltages at the ports of the  $n$ th subnetwork and  $\Delta \mathbf{Y}_n$  is the change in its admittance matrix. The upper bar refers to the adjoint network quantities. Observe that in practice the summation involves only those subnetworks with non zero  $\Delta \mathbf{Y}_n$ , i.e., those who are actually affected by the change.

Substituting the incremental changes with the derivatives with respect to a free parameter  $p$  of the network, (17) becomes

$$\frac{\partial \mathbf{V}_{Ext}^T}{\partial p} \bar{\mathbf{I}}_{Ext} - \frac{\partial \mathbf{I}_{Ext}^T}{\partial p} \bar{\mathbf{V}}_{Ext} \bar{\mathbf{V}}_{Ext} = - \sum_{n=1}^{N-1} \mathbf{V}_n^T \frac{\partial \mathbf{Y}_n^T}{\partial p} \bar{\mathbf{V}}_n. \quad (18)$$

Assuming a constant unit voltage excitation at port  $i$  of the original network and at port  $j$  of the adjoint network, (18) reduces to

$$\frac{\partial \mathbf{I}_{i,j}}{\partial p} = \sum_{n=1}^{N-1} \mathbf{V}_n^{i^T} \frac{\partial \mathbf{Y}_n^T}{\partial p} \mathbf{V}_n^j$$

where  $\mathbf{V}_n^i$  and  $\mathbf{V}_n^j$  are the voltage vectors at the internal ports when the network is excited by a unit voltage at the external port  $i$  or  $j$ , respectively.  $I_{i,j}$  represents the current at port  $i$  due to a unit voltage excitation at port  $j$ . By definition it coincides with the element  $Y_{i,j}^G$  of the admittance matrix of the network. If all subnetworks are reciprocal, we can drop the transpose of the  $\mathbf{Y}_n$  matrix and obtain

$$\frac{\partial \mathbf{Y}_{i,j}^G}{\partial p} = \sum_{n=1}^{N-1} \mathbf{V}_n^{i^T} \frac{\partial \mathbf{Y}_n}{\partial p} \mathbf{V}_n^j. \quad (19)$$

The above formula is the basis for the application of the ANM. The partial derivatives of  $\mathbf{Y}^G$  of the global network are expressed in terms of the partial derivatives of the admittance matrices  $\mathbf{Y}_n$  of constituent subnetworks. The summation in (19) includes all subnetworks, but in practice is restricted to the only subnetworks affected by the parameter  $p$ , since all other derivatives are zero.

It is apparent that the segmentation method described in the previous section lends itself to the implementation of the ANM. The admittance matrices at the right-hand side of (19) are known analytically both for the waveguide Sections III and the stubs IV. The derivatives with respect to all geometrical dimensions can easily be evaluated analytically. The voltage vectors at the connected ports are computed by solving twice the linear system (9) for

$$V_1 = 1; \quad V_N = 0$$

$$V_1 = 0; \quad V_N = 1.$$

This is the only additional analysis effort required for the computation of the derivatives. The computational saving with respect to numerical differentiation is dramatic and is higher the higher the complexity of the microwave structure.

#### IV. RESULTS

A CAD tool has been set up using the ANM in conjunction with the full wave analysis method. High accuracy of the theoretical predictions is obtained thanks to the fullwave models adopted. On the other hand, the gradient-based optimization strategy without numerical differentiation leads to an extremely high efficiency. It should be stressed that the optimization operates directly on the microwave structure rather than on some equivalent circuit, so that the components designed are ready for fabrication.

Several waveguide components, filters, couplers, etc., have been designed with the above described tool. Some examples are illustrated and discussed here.

The computed response of a bandpass waveguide filter using 5 symmetrical H-plane diaphragms (4 cavities), prior and after optimization is shown in Fig. 4. The filter was required to have an attenuation lower than 0.01 dB in the frequency band

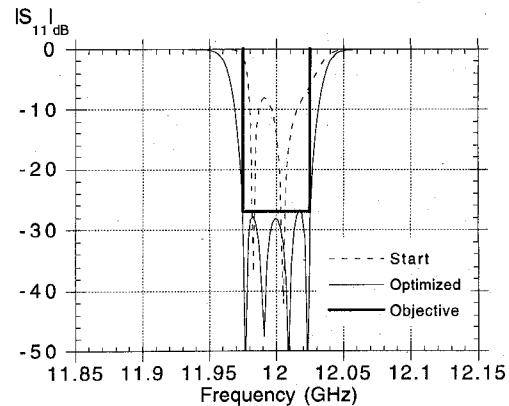
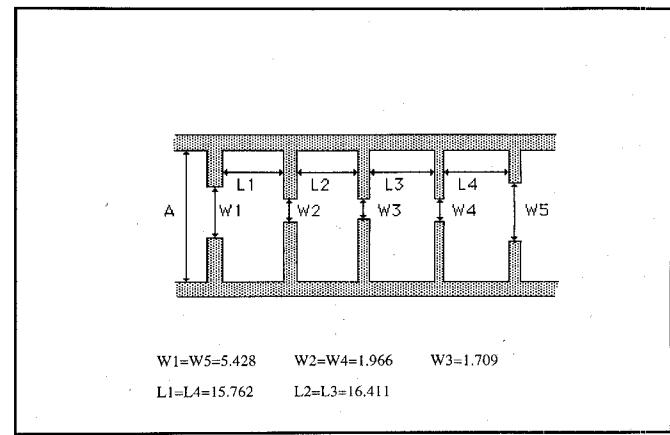


Fig. 4. Responses of a five irises H-plane filter before and after optimization. Design parameters are: Center frequency = 12 GHz; Ripple = 0.01 dB; Bandwidth = 50 MHz, Stopband attenuation -30 dB at  $f = 11.92$  GHz and  $f = 12.08$  GHz. Geometrical dimensions of the filter optimized are given in Table I.

TABLE I  
GEOMETRY OF THE OPTIMIZED FILTER OF FIG. 5(a). DIMENSIONS ARE IN MM.  
METAL THICKNESS OF THE IRISES: 0.1 MM; GUIDE WIDTH:  $A = 19.05$  MM



11.975–12.025 GHz and higher than 30 dB below 11.92 GHz and over 12.08 GHz. The dimensions of the filter optimized are given in Table I. The optimization involved 5 geometrical parameters and was made on 11 frequency points within the passband and 4 points outside the passband. The mode matching analysis used 7 modes for field expansion in the narrowest iris and 60 modes in the waveguide sections. The solution was achieved in 52 iterations, thus required  $52 \times 60 = 780$  single analyses and  $5 \times 780$  derivatives. One complete analysis including derivative computation required approx. 3.5 s on a HP Apollo 715/50 workstation. The entire optimization process took about 45 minutes CPU.

To estimate the efficiency of the present approach compared to the conventional numerical differentiation, we have empirically derived the following relation for the speed-up factor

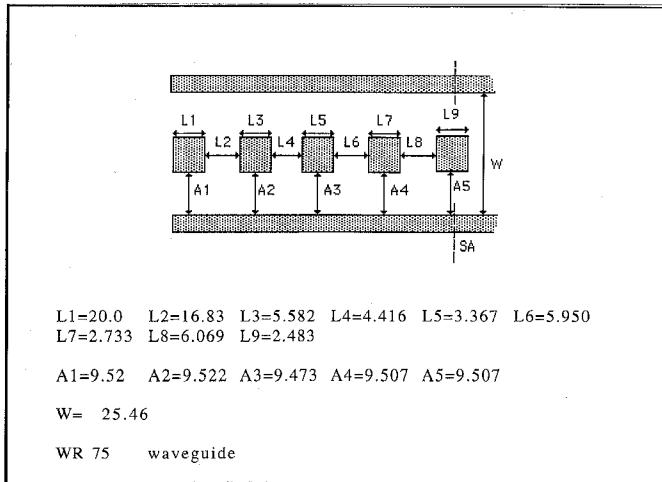
$$S = \frac{T_{FD}}{T_{AN}} = \frac{t_a}{t'_a} (N_{VAR} + 1)$$

where:

- 1)  $T_{FD}$  = CPU time of the optimization using numerical differentiation.

TABLE II

GEOMETRY OF THE OPTIMIZED E-PLANE COUPLER OF FIG. 6. ONLY ONE HALF OF THE STRUCTURE, WHICH IS SYMMETRICAL WITH RESPECT TO THE SA PLANE, IS SHOWN. ALL DIMENSIONS ARE IN MM



- 2)  $T_{AN}$  = CPU time of the optimization using ANM.
- 3)  $t_a$  = CPU time of a single analysis without derivative computation.
- 4)  $t'_a$  = CPU time of a single analysis with derivative computation by ANM.
- 5)  $N_{VAR}$  = number of optimization variables.

We have also found that

$$0.4 < \frac{t_a}{t'_a} < 0.7.$$

In the present example, we found  $t_a/t'_a = 0.6$ . The speedup factor therefore was  $S = 0.6 \times (5 + 1) = 3.6$ . The same optimization using finite difference computation would have therefore required almost 3 hours on the same machine.

The next example refers to a rather more complicated component, a 0 dB branch guide coupler. An initial design was obtained by cascading two four-branch 3 dB couplers. This structure was then optimized to meet the following design specifications in the frequency band 10.75–12.50 GHz: coupling  $|s_{14}| < 0.001$  dB, reflection loss  $|s_{11}| < 40$  dB, isolation  $|s_{13}| < 30$  dB. The number of optimization variables was 13. A speedup factor of about 10 was found. The dimensions of the structure optimized are given in Table II.

Fig. 5 shows the computed responses of the initial and optimized structures compared with the measurements. This figure demonstrates the accuracy of the mode matching predictions and the efficiency of the optimization procedure.

As a final example, a H-plane coupler has been designed and fabricated. The two waveguides are coupled by seven apertures separated by six septa. The device was required to have 3-dB coupling with  $-40$  dB insertion loss in the frequency range 24.5–27.5 GHz. The optimization involved seven geometrical dimensions, corresponding to the distances between septa (four variables) and lengths of the septa (three variables). Thickness of the septa was kept constant. The dimensions of the structure optimized are given in Table III. Fig. 6 shows the theoretical predictions compared with the measurements. The excellent

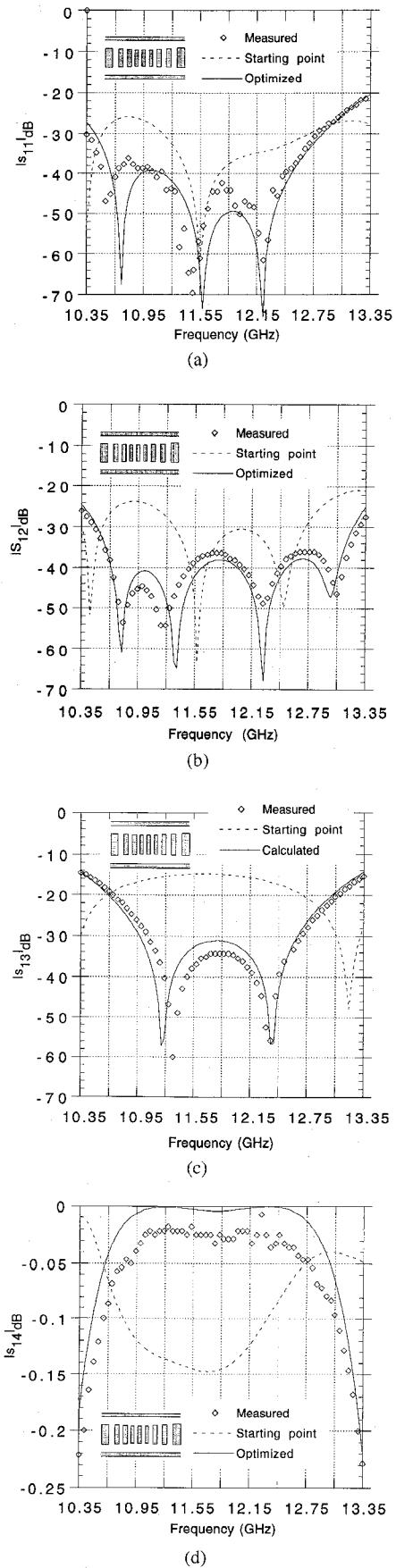


Fig. 5. Experimental and theoretical  $s$ -parameters of a branch guide coupler with eight E-plane branches. Dimensions of the optimized coupler are given in Table II.

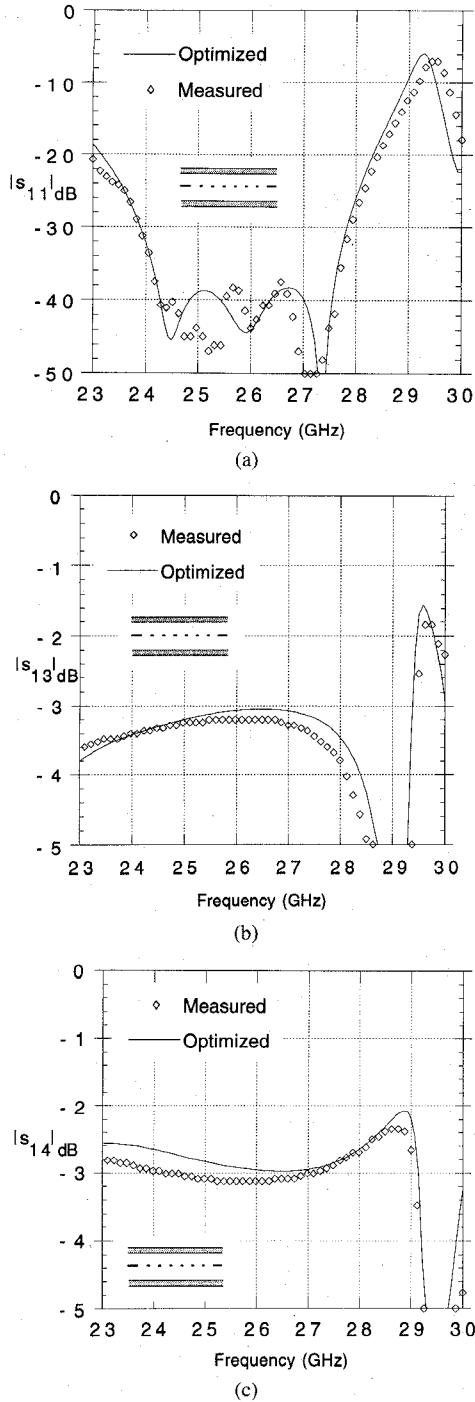


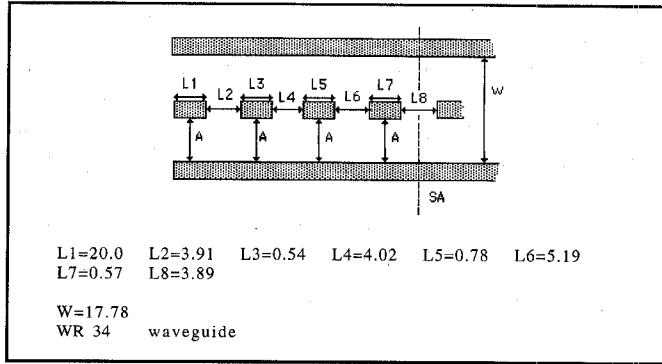
Fig. 6. Experimental and theoretical  $s$ -parameters of a  $H$ -plane coupler with seven apertures.

performance of this device confirm the effectiveness and flexibility of the design tool.

## V. CONCLUSION

A fullwave CAD tool for the design of a class of rectangular waveguide components has been presented. The fullwave mode matching simulator is driven by a quasi-Newton optimizer using the adjoint network method. Since the optimization operates directly on the fullwave microwave model, the component designed is ready for fabrication. With re-

TABLE III  
GEOMETRY OF THE OPTIMIZED  $H$ -PLANE COUPLER OF FIG. 7. ONLY ONE HALF OF THE STRUCTURE, WHICH IS SYMMETRICAL WITH RESPECT TO THE  $SA$  PLANE, IS SHOWN. ALL DIMENSIONS ARE IN MM



spect to the conventional finite difference computation of the derivatives, a speedup factor approximately proportional to the number of optimization variables is achieved.

## APPENDIX

For the reader's convenience, we give the expressions for the coupling matrices (5) used in the evaluation of the  $Y$  matrix of a  $E$ - or  $H$ -plane stub.

For  $E$ -plane discontinuities, assuming  $TE_{10}$  dominant mode excitation, only  $LSE_{1,m}$  modes, are to be used. The transverse electric field of the  $m$ th mode is given by

$$\mathbf{e}_m = \mathbf{y}_o \left[ \sqrt{\frac{2\delta_m}{ab}} \cos\left(\frac{m\pi y}{b}\right) \sin\left(\frac{\pi x}{a}\right) \right] \quad (A1)$$

where  $\delta_m = 1$  for  $m = 0$ ,  $\delta_m = 2$  for  $m > 0$ ,  $a, b$  are the cross-sectional dimensions. Correspondingly, in the expression (1) for the GAM of the waveguide section

$$\beta_m = \sqrt{k_0^2 - \left(\frac{\pi}{a}\right)^2 - \left(\frac{m\pi}{b}\right)^2} \quad (A2)$$

is the phase constant, and

$$Y_{Cm} = \frac{\omega \epsilon}{\beta_m} \frac{\left(\frac{\pi}{a}\right)^2 - k_0^2}{k_0^2} \quad (A3)$$

the characteristic admittance of the mode.

The elements of the coupling matrix (5) are computed from

$$W_{mn} = \sqrt{\frac{2\delta_m}{ab_A}} \sqrt{\frac{2\delta_n}{ab_B}} \int_0^a \sin^2\left(\frac{\pi x}{a}\right) dx \cdot \int_0^{b_A} \cos\left(\frac{m\pi y}{b_A}\right) \cos\left(\frac{n\pi y}{b_B}\right) dy. \quad (A4)$$

For  $H$ -plane discontinuities, assuming  $TE_{10}$  dominant mode excitation, only  $TE_{n,0}$  modes, are to be used. The transverse electric field of the  $n$ th mode is given by

$$\mathbf{e}_m = \mathbf{y}_o \left[ \sqrt{\frac{2}{ab}} \sin\left(\frac{m\pi x}{a}\right) \right]. \quad (A5)$$

Correspondingly, in the expression (1) for the GAM of the waveguide section

$$\beta_m = \sqrt{k_0^2 - \left(\frac{m\pi}{a}\right)^2} \quad (A6)$$

is the phase constant, and

$$Y_{Cm} = \frac{\beta_m}{\omega\mu} \quad (A7)$$

the characteristic admittance of the mode.

The elements of the coupling matrix (5) are computed from

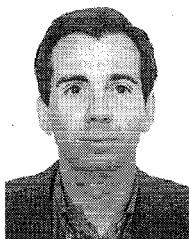
$$W_{mn} = \sqrt{\frac{2}{a_A b}} \sqrt{\frac{2}{a_B b}} \int_0^b dy \int_0^{a_A} \sin\left(\frac{m\pi y}{a_A}\right) \sin\left(\frac{n\pi y}{a_B}\right) dx. \quad (A8)$$

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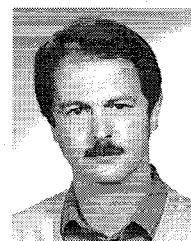


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